



# Homework #11

**Problems 6.7, 6.8, 6.28, 6.29,  
and 6.32**



## Problem 6.7

Consider an *npn* transistor whose base-emitter drop is 0.76 V at a collector current of 5 mA. What current will it conduct at  $v_{BE} = 0.70$  V? What is its base-emitter voltage for  $I_C = 5 \mu\text{A}$ ?

$$V_{BE} = 0.76 \text{ V} \quad V_T = 0.025 \text{ V} \quad I_C = 5 \text{ mA} = I_S e^{V_{BE}/V_T}$$

$$I_S = \frac{5 \text{ mA}}{e^{V_{BE}/V_T}} = 3.137 \times 10^{-16} \text{ A}$$

$$V_{BE} = 0.7 \text{ V}$$

$$I_C = I_S e^{V_{BE}/V_T} = 3.137 \times 10^{-16} e^{700/25} = 453.59 \mu\text{A}$$

$$I_C = 5 \mu\text{A}$$

$$V_{BE} = V_T \ln \left( \frac{I_C}{I_S} \right) = .025 \ln \left( \frac{10 \times 10^{-6}}{3.137 \times 10^{-16}} \right) = 0.587 \text{ V}$$



## Problem 6.8

In a particular BJT, the base current is  $10\ \mu\text{A}$ , and the collector current is  $800\ \mu\text{A}$ . Find  $\beta$  and  $\alpha$  for this device.

$$\beta \equiv \frac{i_C}{i_B}$$

$\beta$  is the common-emitter  
current gain

$$\alpha \equiv \frac{i_C}{i_E}$$

$\alpha$  is the common-base current  
gain

$$i_B = \frac{i_C}{\beta}$$

$$\beta = \frac{i_C}{i_B} = \frac{800\ \mu\text{A}}{10\ \mu\text{A}} = 80$$

$$\alpha = \frac{\beta}{\beta + 1} = \frac{80}{80 + 1} = 0.9877$$

$$\alpha \equiv \frac{i_C}{i_E} = \frac{i_C}{i_C + i_B} = \frac{800\ \mu\text{A}}{810\ \mu\text{A}} = 0.9877$$

# Problem 6.28

For the circuits in Fig. P6.28, assume that the transistors have very large  $\beta$ . Some measurements have been made on these circuits, with the results indicated in the figure. Find the values of the other labeled voltages and currents.

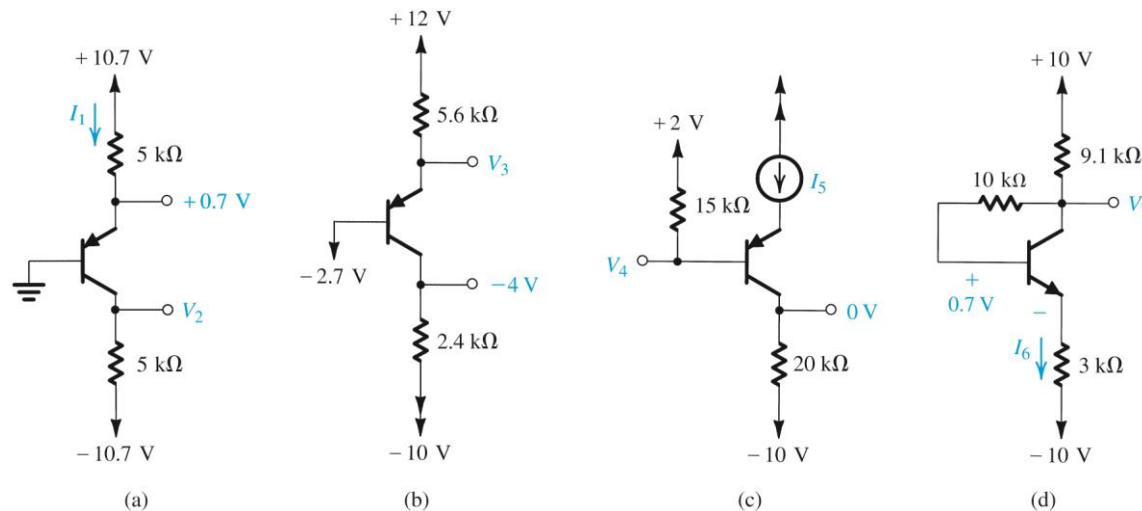


Figure P6.28

# Problem 6.28a

For the circuits in Fig. P6.28, assume that the transistors have very large  $\beta$ . Some measurements have been made on these circuits, with the results indicated in the figure. Find the values of the other labeled voltages and currents.

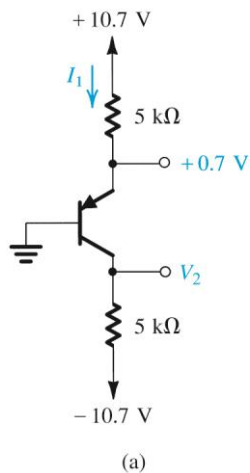


Figure P6.28

$$\beta \equiv \frac{i_C}{i_B} \Rightarrow i_B = \frac{i_C}{\beta}$$

Very large  $\beta$  means  $I_E = I_C$  ( $I_B \approx 0$ )

$$I_1 = I_E = \frac{10.7 \text{ V} - 0.7 \text{ V}}{10 \text{ k}\Omega} = 2 \text{ mA}$$

$$V_2 = V_C = -10.7 \text{ V} + 5 \text{ k}\Omega \times 2 \text{ mA} = -0.7 \text{ V}$$



## Problem 6.28b

For the circuits in Fig. P6.28, assume that the transistors have very large  $\beta$ . Some measurements have been made on these circuits, with the results indicated in the figure. Find the values of the other labeled voltages and currents.

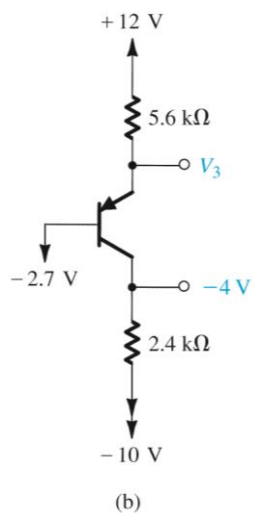


Figure P6.28

Very large  $\beta$  means  $I_E = I_C$  ( $I_B \approx 0$ )

$$I_E = I_C = \frac{-4 \text{ V} - -10 \text{ V}}{2.4 \text{ k}\Omega} = 2.5 \text{ mA}$$

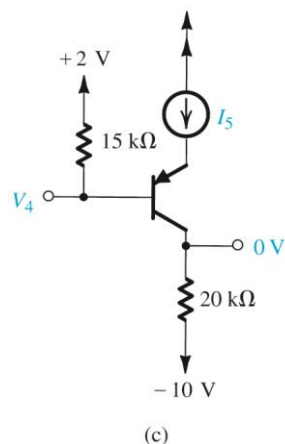
$$V_3 = V_E = 12 \text{ V} - 5.6 \text{ k}\Omega \times 2.5 \text{ mA} = -2 \text{ V}$$



## Problem 6.28c

For the circuits in Fig. P6.28, assume that the transistors have very large  $\beta$ . Some measurements have been made on these circuits, with the results indicated in the figure. Find the values of the other labeled voltages and currents.

Very large  $\beta$  means  $I_E = I_C$  ( $I_B \approx 0$ )



$$I_5 = I_E = \frac{10 \text{ V}}{20 \text{ k}\Omega} = 0.5 \text{ mA}$$

$$V_4 = V_B = 2 \text{ V}$$

Figure P6.28



# Problem 6.28d

For the circuits in Fig. P6.28, assume that the transistors have very large  $\beta$ . Some measurements have been made on these circuits, with the results indicated in the figure. Find the values of the other labeled voltages and currents.

Very large  $\beta$  means  $I_E = I_C$  ( $I_B \approx 0$ )

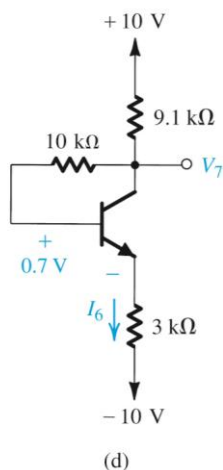


Figure P6.28

$$I_6 = I_E = I_C = \frac{V_B - 0.7V + 10V}{3\text{ k}\Omega} = \frac{10V - V_C}{9.1\text{ k}\Omega}$$

$$9.1\text{ k}\Omega(V_B + 9.3V) = 3\text{ k}\Omega(10V - V_C)$$

$$9.1V_B + 84.63 = 30 - 3V_C$$

$$V_7 = V_C = V_B$$

$$12.1V_7 = -54.63$$

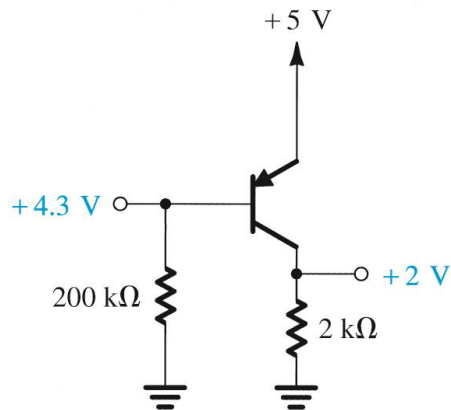
$$V_7 = -4.515V$$

$$I_6 = I_E = I_C = \frac{10V + 4.515}{9.1\text{ k}\Omega} = 1.595\text{ mA}$$



# Problem 6.29a,b

Measurements on the circuits of Fig. P6.29 produce labeled voltages as indicated. Find the value of  $\beta$  for each transistor.



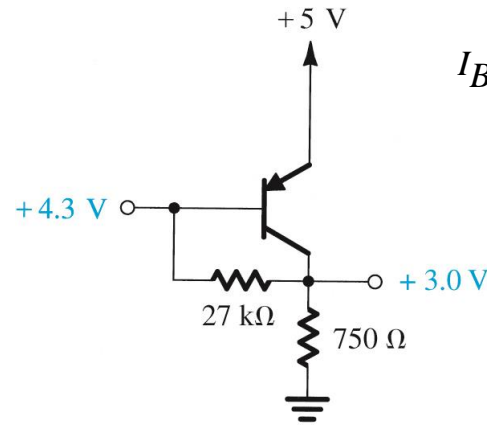
(a)

Figure P6.29

$$I_C := \frac{2V}{2k\Omega} = 1mA$$

$$I_B := \frac{4.3V}{200k\Omega} = 21.5\mu A$$

$$\beta := \frac{I_C}{I_B} = 46.512$$



(b)

$$I_B := \frac{4.3V - 3.0V}{27k\Omega} = 48.148\mu A$$

$$I_R := \frac{3V}{750\Omega} = 4mA$$

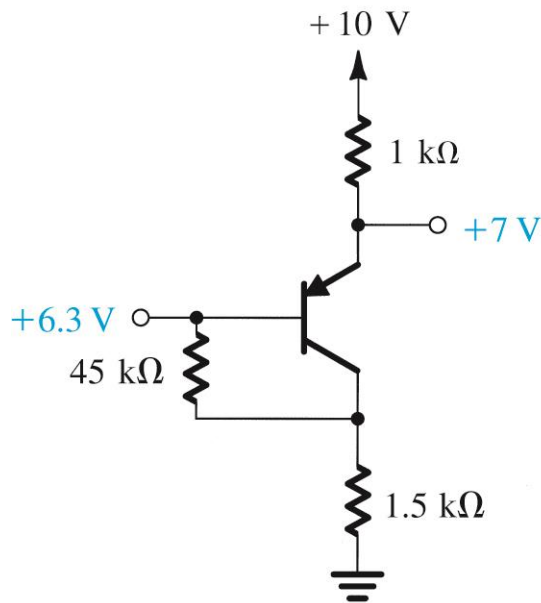
$$I_C := I_R - I_B = 3.952mA$$

$$\beta := \frac{I_C}{I_B} = 82.077$$



## Problem 6.29c

Measurements on the circuits of Fig. P6.29 produce labeled voltages as indicated. Find the value of  $\beta$  for each transistor.



(c)

Figure P6.29

$$I_E = \frac{10 \text{ V} - 7 \text{ V}}{1 \text{ k}\Omega} = 3 \text{ mA}$$

$$I_E = I_C + I_B$$

$$V_C = (I_C + I_B)1.5 \text{ k}\Omega = 3 \text{ mA} \times 1.5 \text{ k}\Omega = 4.5 \text{ V}$$

$$I_B = \frac{6.3 \text{ V} - 4.5 \text{ V}}{45 \text{ k}\Omega} = 40 \mu\text{A}$$

$$I_C = 3 \text{ mA} - 40 \mu\text{A} = 2.96 \text{ mA}$$

$$\beta = \frac{i_C}{i_B} = \frac{2.96 \text{ mA}}{40 \mu\text{A}} = 74$$



# Problem 6.32a

Design the circuit in Fig. P6.32 to establish a current of 0.5 mA in the emitter and a voltage of -0.5 V at the collector. The transistor  $v_{EB} = 0.64$  V at  $I_E = 0.1$  mA, and  $\beta = 100$ . To what value can  $R_C$  be increased while the collector current remains unchanged?

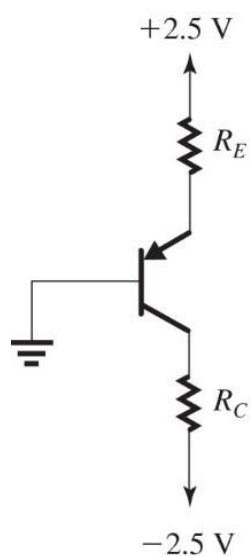


Figure P6.32

$$\beta := 100$$

$$\alpha := \frac{\beta}{\beta + 1} = 0.9901$$

$$V_{EB} := 0.64 \text{ V}$$

$$I_E := 0.1 \text{ mA}$$

## Method 1

$$I_C := \alpha I_E = 0.099 \text{ mA}$$

$$I_S := I_C \cdot e^{\frac{-V_{EB}}{V_T}} = 0.755 \text{ fA}$$

$$I_E := 0.5 \text{ mA}$$

$$I_C := \alpha I_E = 0.495 \text{ mA}$$

$$V_{EB} := V_T \cdot \ln\left(\frac{I_C}{I_S}\right) = 0.68 \text{ V}$$

## Method 2

$$\frac{I_{E2}}{I_{E1}} = \frac{\alpha I_S e^{V_{EB2}/V_T}}{\alpha I_S e^{V_{EB1}/V_T}} = e^{(V_{EB2} - V_{EB1})/V_T} \Rightarrow V_{EB2} = V_T \ln\left(\frac{I_{E2}}{I_{E1}}\right) + V_{EB1}$$

$$V_{EB} := 25 \text{ mV} \cdot \ln\left(\frac{0.5 \text{ mA}}{0.1 \text{ mA}}\right) + 0.64 \text{ V} = 0.68 \text{ V}$$

# Problem 6.32b

Design the circuit in Fig. P6.32 to establish a current of 0.5 mA in the emitter and a voltage of -0.5 V at the collector. The transistor  $v_{EB} = 0.64$  V at  $I_E = 0.1$  mA, and  $\beta = 100$ . To what value can  $R_C$  be increased while the collector current remains unchanged?

$$V_{EB} = 0.68 \text{ V}$$

$$R_E = \frac{2.5 \text{ V} - 0.68 \text{ V}}{0.5 \text{ mA}} = 3.64 \text{ k}\Omega$$

$$R_C = \frac{-0.5 \text{ V} - -2.5 \text{ V}}{0.495 \text{ mA}} = 4.04 \text{ k}\Omega$$

The voltage at the collector can be increased to 0.4 V and remain in the active mode. Therefore,  $R_C$  can increase to  $\approx 5.9 \text{ k}\Omega$  and the collector current will remain unchanged.

$$R_{Cmax} = \frac{0.4 \text{ V} - -2.5 \text{ V}}{0.495 \text{ mA}} = 5.86 \text{ k}\Omega$$

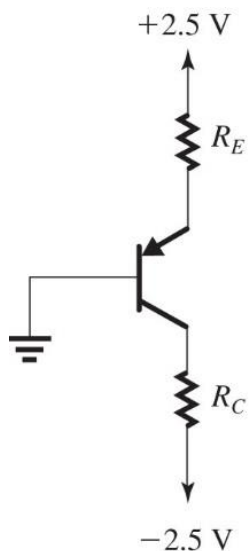


Figure P6.32